Technical Data

3.3 V ECL/PECL/HSTL/LVDS ÷2/4, ÷4/6 Clock Generation Chip

The MC100ES6039 is a low skew $\div 2/4$, $\div 4/6$ clock generation chip designed explicitly for low skew clock generation applications. The internal dividers are synchronous to each other, therefore, the common output edges are all precisely aligned. The device can be driven by either a differential or single-ended ECL or, if positive power supplies are used, LVPECL input signals. In addition, by using the V_{BB} output, a sinusoidal source can be AC coupled into the device.

The common enable $(\overline{\text{EN}})$ is synchronous so that the internal dividers will only be enabled/disabled when the internal clock is already in the LOW state. This avoids any chance of generating a runt clock pulse on the internal clock when the device is enabled/disabled as can happen with an asynchronous control. The internal enable flip-flop is clocked on the falling edge of the input clock, therefore, all associated specification limits are referenced to the negative edge of the clock input.

Upon startup, the internal flip-flops will attain a random state; therefore, for systems which utilize multiple ES6039s, the master reset (MR) input must be asserted to ensure synchronization. For systems which only use one ES6039, the MR pin need not be exercised as the internal divider design ensures synchronization between the $\pm 2/4$ and the $\pm 4/6$ outputs of a single device. All V_{CC} and V_{EE} pins must be externally connected to power supply to guarantee proper operation.

The 100ES Series contains temperature compensation.

Features

- Maximum Frequency >1.0 GHz Typical
- 50 ps Output-to-Output Skew
- PECL Mode Operating Range: V_{CC} = 3.135 V to 3.8 V with V_{EE} = 0 V
- ECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -3.135 V to -3.8 V
- · Open Input Default State
- · Synchronous Enable/Disable
- · Master Reset for Synchronization of Multiple Chips
- V_{BB} Output
- LVDS and HSTL Input Compatible
- · 20-Lead Pb-Free Package Available

MC100ES6039



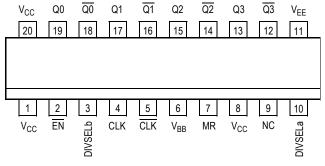
DW SUFFIX 20-LEAD SOIC PACKAGE CASE 751D-07



EG SUFFIX 20-LEAD TSSOP PACKAGE Pb-FREE PACKAGE CASE 751D-07

| ORDERING INFORMATION | | | | | | |
|----------------------|-----------------|--|--|--|--|--|
| Device Package | | | | | | |
| MC100ES6039DW | SO-20 | | | | | |
| MC100ES6039DWR2 | SO-20 | | | | | |
| MC100ES6039EG | SO-20 (Pb-Free) | | | | | |
| MC100ES6039EGR2 | SO-20 (Pb-Free) | | | | | |





Warning: All V_{CC} and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

Figure 1. 20-Lead Pinout (Top View)

Table 1. Pin Description

| Pin | Function |
|---|-----------------------------|
| CLK ⁽¹⁾ , CLK ⁽¹⁾ | ECL Diff Clock Inputs |
| EN ⁽¹⁾ | ECL Sync Enable |
| MR ⁽¹⁾ | ECL Master Reset |
| V _{BB} | ECL Reference Output |
| Q0, Q1, Q0, Q1 | ECL Diff ÷2/4 Outputs |
| Q2, Q3, Q2, Q3 | ECL Diff ÷4/6 Outputs |
| DIVSELa ⁽¹⁾ | ECL Freq. Select Input ÷2/4 |
| DIVSELb ⁽¹⁾ | ECL Freq. Select Input ÷4/6 |
| V _{CC} | ECL Positive Supply |
| V _{EE} | ECL Negative Supply |
| NC | No Connect |

1. Pins will default low when left open.

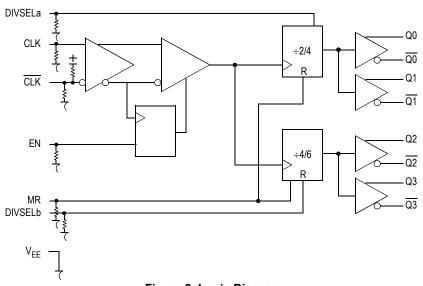


Figure 2. Logic Diagram

Table 2. Function Tables

| CLK | EN | MR | Function |
|-----|----|----|------------|
| Z | L | L | Divide |
| ZZ | Н | L | Hold Q0:3 |
| X | X | Н | Reset Q0:3 |

X = Don't Care

Z = Low-to-High Transition

ZZ = High-to-Low Transition

| DIVSELa | Q0:1 Outputs |
|---------|--------------|
| L | Divide by 2 |
| Н | Divide by 4 |
| DIVSELb | Q2:3 Outputs |
| L | Divide by 4 |
| Н | Divide by 6 |

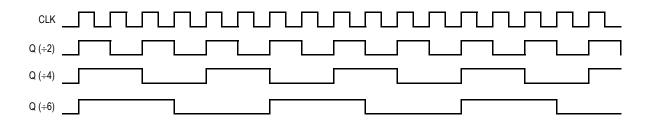


Figure 3. Timing Diagram

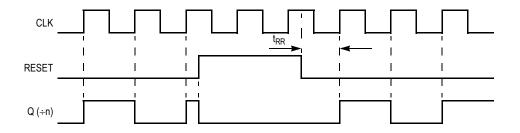


Figure 4. Timing Diagram

Table 3. Attributes

| Characteristics | Value | |
|----------------------------------|---|-----------------------------|
| Internal Input Pulldown Resistor | 75 kΩ | |
| Internal Input Pullup Resistor | 75 kΩ | |
| ESD Protection | Human Body Model Machine Model Charged Device Model | > 4 kV > 200 V > 2 kV |

Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test

Table 4. Maximum Ratings⁽¹⁾

| Symbol | Parameter | Condition 1 | Condition 2 | Rating | Units |
|-------------------|---|--|------------------------------------|-------------|--------------|
| V _{CC} | PECL Mode Power Supply | V _{EE} = 0 V | | 3.9 | V |
| V _{EE} | ECL Mode Power Supply | V _{CC} = 0 V | | -3.9 | V |
| VI | PECL Mode Input Voltage ECL Mode Input Voltage | V _{EE} = 0 V V _{CC} = 0 V | $V_I \le V_{CC} \\ V_I \ge V_{EE}$ | 3.9 -3.9 | V |
| l _{out} | Output Current | Continuous Surge | | 50 100 | mA mA |
| I _{BB} | V _{BB} Sink/Source | | | ± 0.5 | mA |
| T _A | Operating Temperature Range | | | -40 to +85 | °C |
| T _{stg} | Storage Temperature Range | | | -65 to +150 | °C |
| $\theta_{\sf JA}$ | Thermal Resistance (Junction-to-Ambient) | 0 LFPM 500 LFPM | 20 SOIC 20 SOIC | TBD TBD | °C/W °C/W |

^{1.} Maximum Ratings are those values beyond which device damage may occur.

Table 5. DC Characteristics ($V_{CC} = 0 \text{ V}, V_{EE} = -3.8 \text{ V} \text{ to } -3.135 \text{ V} \text{ or } V_{CC} = 3.135 \text{ V} \text{ to } 3.8 \text{ V}, V_{EE} = 0 \text{ V})$ ⁽¹⁾

| Characteristic | −40°C | | | 0°C to 85°C | | | Unit |
|---|--|--|--|--|---|--|--|
| | Min | Тур | Max | Min | Тур | Max | Unit |
| Power Supply Current | | 35 | 60 | | 35 | 60 | mA |
| Output HIGH Voltage ⁽²⁾ | V _{CC} –1150 | V _{CC} –1020 | V _{CC} -800 | V _{CC} –1200 | V _{CC} –970 | V _{CC} –750 | mV |
| Output LOW Voltage ⁽²⁾ | V _{CC} –1950 | V _{CC} –1620 | V _{CC} –1250 | V _{CC} –2000 | V _{CC} –1680 | V _{CC} –1300 | mV |
| Input HIGH Voltage (Single-Ended) | V _{CC} –1165 | | V _{CC} -880 | V _{CC} –1165 | | V _{CC} –880 | mV |
| Input LOW Voltage (Single-Ended) | V _{CC} –1810 | | V _{CC} –1475 | V _{CC} –1810 | | V _{CC} –1475 | mV |
| Output Reference Voltage | V _{CC} –1400 | | V _{CC} –1200 | V _{CC} –1400 | | V _{CC} –1200 | mV |
| Differential Input Voltage ⁽³⁾ | 0.12 | | 1.4 | 0.12 | | 1.4 | V |
| Differential Cross Point Voltage ⁽⁴⁾ | V _{EE} +0.2 | | V _{CC} -0.7 | V _{EE} +0.2 | | V _{CC} -0.7 | V |
| Input HIGH Current | | | 150 | | | 150 | μΑ |
| Input LOW Current | 0.5 | | | 0.5 | | | μΑ |
| | Power Supply Current Output HIGH Voltage ⁽²⁾ Output LOW Voltage ⁽²⁾ Input HIGH Voltage (Single-Ended) Input LOW Voltage (Single-Ended) Output Reference Voltage Differential Input Voltage ⁽³⁾ Differential Cross Point Voltage ⁽⁴⁾ Input HIGH Current | $\begin{array}{c c} & \textbf{Min} \\ \\ \text{Power Supply Current} \\ \\ \text{Output HIGH Voltage}^{(2)} & V_{\text{CC}} - 1150 \\ \\ \text{Output LOW Voltage}^{(2)} & V_{\text{CC}} - 1950 \\ \\ \text{Input HIGH Voltage (Single-Ended)} & V_{\text{CC}} - 1165 \\ \\ \text{Input LOW Voltage (Single-Ended)} & V_{\text{CC}} - 1810 \\ \\ \text{Output Reference Voltage} & V_{\text{CC}} - 1400 \\ \\ \text{Differential Input Voltage}^{(3)} & 0.12 \\ \\ \text{Differential Cross Point Voltage}^{(4)} & V_{\text{EE}} + 0.2 \\ \\ \text{Input HIGH Current} & \\ \end{array}$ | $ \begin{array}{ c c c c } \hline \textbf{Min} & \textbf{Typ} \\ \hline Power Supply Current & 35 \\ \hline Output HIGH Voltage^{(2)} & V_{CC} -1150 & V_{CC} -1020 \\ \hline Output LOW Voltage^{(2)} & V_{CC} -1950 & V_{CC} -1620 \\ \hline Input HIGH Voltage (Single-Ended) & V_{CC} -1165 \\ \hline Input LOW Voltage (Single-Ended) & V_{CC} -1810 \\ \hline Output Reference Voltage & V_{CC} -1400 \\ \hline Differential Input Voltage^{(3)} & 0.12 \\ \hline Differential Cross Point Voltage^{(4)} & V_{EE} + 0.2 \\ \hline Input HIGH Current & & & \\ \hline \end{array} $ | $ \begin{array}{ c c c c c } \hline \textbf{Min} & \textbf{Typ} & \textbf{Max} \\ \hline Power Supply Current & 35 & 60 \\ \hline Output HIGH Voltage^{(2)} & V_{CC}-1150 & V_{CC}-1020 & V_{CC}-800 \\ \hline Output LOW Voltage^{(2)} & V_{CC}-1950 & V_{CC}-1620 & V_{CC}-1250 \\ \hline Input HIGH Voltage (Single-Ended) & V_{CC}-1165 & V_{CC}-880 \\ \hline Input LOW Voltage (Single-Ended) & V_{CC}-1810 & V_{CC}-1475 \\ \hline Output Reference Voltage & V_{CC}-1400 & V_{CC}-1200 \\ \hline Differential Input Voltage^{(3)} & 0.12 & 1.4 \\ \hline Differential Cross Point Voltage^{(4)} & V_{EE}+0.2 & V_{CC}-0.7 \\ \hline Input HIGH Current & 150 \\ \hline \end{array} $ | Characteristic Min Typ Max Min Power Supply Current 35 60 60 Output HIGH Voltage ⁽²⁾ V _{CC} −1150 V _{CC} −1020 V _{CC} −800 V _{CC} −1200 Output LOW Voltage ⁽²⁾ V _{CC} −1950 V _{CC} −1620 V _{CC} −1250 V _{CC} −2000 Input HIGH Voltage (Single-Ended) V _{CC} −1165 V _{CC} −880 V _{CC} −1165 Input LOW Voltage (Single-Ended) V _{CC} −1810 V _{CC} −1475 V _{CC} −1810 Output Reference Voltage V _{CC} −1400 V _{CC} −1200 V _{CC} −1400 Differential Input Voltage ⁽³⁾ 0.12 1.4 0.12 Differential Cross Point Voltage ⁽⁴⁾ V _{EE} +0.2 V _{CC} −0.7 V _{EE} +0.2 Input HIGH Current 150 150 | Characteristic Min Typ Max Min Typ Power Supply Current 35 60 35 Output HIGH Voltage ⁽²⁾ V _{CC} −1150 V _{CC} −1020 V _{CC} −800 V _{CC} −1200 V _{CC} −970 Output LOW Voltage ⁽²⁾ V _{CC} −1950 V _{CC} −1620 V _{CC} −1250 V _{CC} −2000 V _{CC} −1680 Input HIGH Voltage (Single-Ended) V _{CC} −1165 V _{CC} −880 V _{CC} −1165 V _{CC} −1165 Input LOW Voltage (Single-Ended) V _{CC} −1810 V _{CC} −1475 V _{CC} −1810 V _{CC} −1475 Output Reference Voltage V _{CC} −1400 V _{CC} −1200 V _{CC} −1400 V _{CC} −1400 Differential Input Voltage ⁽³⁾ 0.12 1.4 0.12 1.4 Differential Cross Point Voltage ⁽⁴⁾ V _{EE} +0.2 V _{CC} -0.7 V _{EE} +0.2 Input HIGH Current 150 150 | Characteristic Min Typ Max Min Typ Max Power Supply Current 35 60 35 60 Output HIGH Voltage ⁽²⁾ V _{CC} -1150 V _{CC} -1020 V _{CC} -800 V _{CC} -1200 V _{CC} -970 V _{CC} -750 Output LOW Voltage ⁽²⁾ V _{CC} -1950 V _{CC} -1620 V _{CC} -1250 V _{CC} -2000 V _{CC} -1680 V _{CC} -1300 Input HIGH Voltage (Single-Ended) V _{CC} -1165 V _{CC} -880 V _{CC} -1165 V _{CC} -880 Input LOW Voltage (Single-Ended) V _{CC} -1810 V _{CC} -1475 V _{CC} -1810 V _{CC} -1475 Output Reference Voltage V _{CC} -1400 V _{CC} -1200 V _{CC} -1400 V _{CC} -1200 Differential Input Voltage ⁽³⁾ 0.12 1.4 0.12 1.4 Differential Cross Point Voltage ⁽⁴⁾ V _{EE} +0.2 V _{CC} -0.7 V _{EE} +0.2 V _{CC} -0.7 Input HIGH Current 150 150 |

^{1.} MC100ES6139 circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.

^{2.} All loading with 50 Ω to $\mbox{V}_{\mbox{CC}}\mbox{--}2.0$ volts.

^{3.} V_{PP} (DC) is the minimum differential input voltage swing required to maintain device functionality.

^{4.} V_{CMR} (DC) is the crosspoint of the differential input signal. Functional operation is obtained when the crosspoint is within the V_{CMR} (DC) range and the input swing lies within the V_{PP} (DC) specification.

Table 6. AC Characteristics ($V_{CC} = 0 \text{ V}, V_{EE} = -3.8 \text{ V} \text{ to } -3.135 \text{ V} \text{ or } V_{CC} = 3.135 \text{ V} \text{ to } 3.8 \text{ V}, V_{EE} = 0 \text{ V})$ ⁽¹⁾

| Cumbal | Characteristic | | | -40°C | | 25°C | | | 85°C | | | Unit |
|--|---|------------------------|----------------------|------------|----------------------|----------------------|------------|----------------------|----------------------|------------|----------------------|----------------|
| Symbol | | | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Unit |
| f _{max} | Maximum Frequenc | су | | > 1 | | | > 1 | | | > 1 | | GHz |
| t _{PLH} , t _{PHL} | Propagation Delay | CLK, Q (Diff) MR, Q | 575 500 | | 875 850 | 575 500 | | 875 850 | 575 500 | | 875 850 | ps ps |
| t _{RR} | Reset Recovery | | 200 | 100 | | 200 | 100 | | 200 | 100 | | ps |
| t _s | Setup Time | EN, CLK DIVSEL, CLK | 200 400 | 120 180 | | 200 400 | 120 180 | | 200 400 | 120 180 | | ps ps |
| t _h | Hold Time | CLK, EN CLK, DIVSEL | 100 200 | 50 140 | | 100 200 | 50 140 | | 100 200 | 50 140 | | ps ps |
| t _{PW} | Minimum Pulse Wid | dth MR | 550 | 450 | | 550 | 450 | | 550 | 450 | | ps |
| t _{SKEW} | Within Device Skev Q, Q @ Sa Device-to-Device S | me Frequency | | | 80 50 300 | | | 80 50 300 | | | 80 50 300 | ps ps ps |
| t _{JITTER} | Cycle-to-Cycle Jitte | r (RMS 1σ) | | | 1 | | | 1 | | | 1 | ps |
| V _{PP} | Input Voltage Swing | g (Differential) | 150 | | 1400 | 150 | | 1400 | 150 | | 1400 | mV |
| V _{CMR} | Differential Cross P | oint Voltage | V _{EE} +0.2 | | V _{CC} -1.1 | V _{EE} +0.2 | | V _{CC} -1.1 | V _{EE} +0.2 | | V _{CC} -1.1 | V |
| t _r | Output Rise/Fall Tir (20% – 80%) | mes Q, \overline{Q} | 50 | | 300 | 50 | | 300 | 50 | | 300 | ps |

- 1. Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50 Ω to V_{CC} –2.0 V.

 2. Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

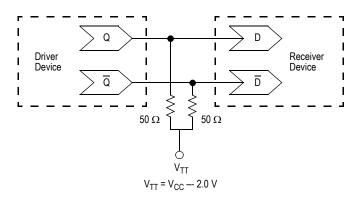
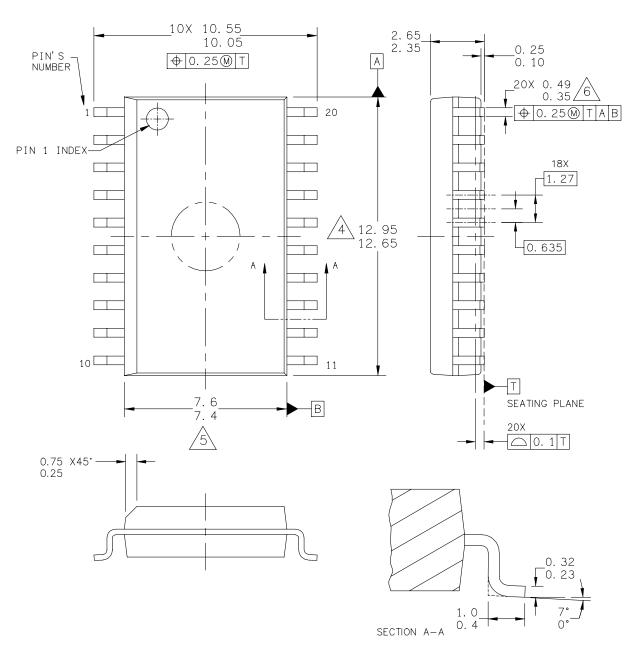


Figure 5. Typical Termination for Output Driver and Device Evaluation

PACKAGE DIMENSIONS



| © FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. | MECHANICAL OUTLINE | | PRINT VERSION NO | OT TO SCALE |
|---|--------------------|----------------|------------------|-------------|
| TITLE: | DOCUMENT NO |): 98ASB42343B | REV: J | |
| 20LD SOIC W/B, 1.27 PITCH | | CASE NUMBER | R: 751D-07 | 23 MAR 2005 |
| CASE-001E1 | STANDARD: JE | EDEC MS-013AC | | |

PAGE 1 OF 2

CASE 751D-07 ISSUE J 20-LEAD SOIC PACKAGE

PACKAGE DIMENSIONS

NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. DATUMS A AND B TO BE DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT THE PLASTIC BODY.



 \cancel{A} This dimension does not include mold flash, protrusion or gate burrs. Mold FLASH, PROTRUSION OR GATE BURRS SHALL NOT EXCEED 0.15 MM PER SIDE. THIS DIMENSION IS DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT THE PLASTIC BODY.



/Ś.\ THIS DIMENSION DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSIONS. INTER-LEAD FLASH AND PROTRUSIONS SHALL NOT EXCEED 0.25 MM PER SIDE. THIS DIMENSION IS DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT THE PLASTIC BODY.

/6\ THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.62 mm.

| © FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. | MECHANICA | L OUTLINE | PRINT VERSION NO | OT TO SCALE |
|--|-------------|----------------|------------------|-------------|
| TITLE: | DOCUMENT NO |): 98ASB42343B | REV: J | |
| 20LD SOIC W/B, 1.27 PITCH, | | CASE NUMBER | R: 751D-07 | 23 MAR 2005 |
| C//SL OOTLIN | | STANDARD: JE | IDEC MS-013AC | |

PAGE 2 OF 2

CASE 751D-07 ISSUE J 20-LEAD SOIC PACKAGE

MC100ES6039

How to Reach Us:

Home Page:

www.freescale.com

E-mail:

support@freescale.com

USA/Europe or Locations Not Listed:

Freescale Semiconductor Technical Information Center, CH370 1300 N. Alma School Road Chandler, Arizona 85224 +1-800-521-6274 or +1-480-768-2130 support@freescale.com

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) support@freescale.com

Japan:

Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064 Japan 0120 191014 or +81 3 5437 9125 support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd. Technical Information Center 2 Dai King Street
Tai Po Industrial Estate
Tai Po, N.T., Hong Kong
+800 2666 8080
support.asia@freescale.com

For Literature Requests Only:

Freescale Semiconductor Literature Distribution Center P.O. Box 5405
Denver, Colorado 80217
1-800-441-2447 or 303-675-2140
Fax: 303-675-2150
LDCForFreescaleSemiconductor@hibbertgroup.com

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale™ and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.

© Freescale Semiconductor, Inc. 2005. All rights reserved.

